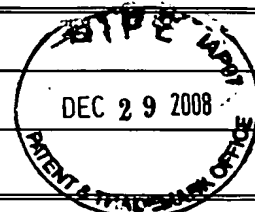


Form PTO 1449  U.S. Department of Commerce Patent and Trademark Office  Information Disclosure Statement by Applicant	ATTY. DOCKET NUMBER <b>HIRA.0217</b>	SERIAL NUMBER <b>10/565,624</b>
	APPLICANT <b>Suda et al.</b>	
	FILING DATE <b>January 24, 2006</b>	GROUP <b>2826</b>



## U.S. Patent Documents

Examiner Initial	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE

## Foreign Patent Documents

Examiner Initial	DOCUMENT NUMBER	FILING DATE	COUNTRY	CLASS	SUB- CLASS	TRANSLATION	
						YES	NO
	2000-150875	11/13/1998	Japan			Abstract	X

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